1 GB Registered SDRAM DIMM 128-Mword × 72-bit, 133 MHz Memory Bus, 2-Bank Module

> (36 pcs of 64 M × 4 Components) PC133 SDRAM

HITACHI

ADE-203-1079A (Z) Preliminary Rev. 0.1 Aug. 10, 1999

Description

The HB52RF1289E2 belongs to 8-byte DIMM (Dual In-line Memory Module) family, and has been developed as an optimized main memory solution for 8-byte processor applications. The HB52RF1289E2 is a 64M \times 72 \times 2-bank Synchronous Dynamic RAM Module, mounted 36 pieces of 256-Mbit SDRAM (HM5225405BTB) sealed in TCP package, 1 piece of PLL clock driver, 3 pieces register driver and 1 piece of serial EEPROM (2-kbit) for Presence Detect (PD). An outline of the HB52RF1289E2 is 168-pin socket type package (dual lead out). Therefore, the HB52RF1289E2 makes high density mounting possible without surface mount technology. The HB52RF1289E2 provides common data inputs and outputs. Decoupling capacitors are mounted beside TCP on the module board.

Note: Do not push the cover or drop the modules in order to protect from mechanical defects, which would be electrical defects.

Features

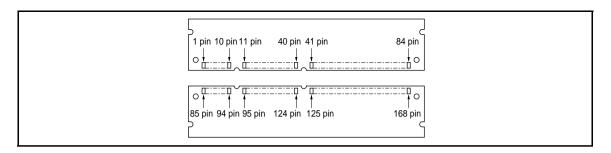
- Fully compatible with: JEDEC standard outline 8-byte DIMM
- 168-pin socket type package (dual lead out)
 - Outline: 133.37 mm (length) \times 38.10 mm (Height) \times 4.80 mm (Thickness)
 - Lead pitch: 1.27 mm
- 3.3 V power supply
- Clock frequency: 133 MHz (max)
- LVTTL interface
- Data bus width: ×72ECC
- Single pulsed RAS
- 4 Banks can operates simultaneously and independently
- Burst read/write operation and burst read/single write operation capability
- Programmable burst length: 1/2/4/8
 - 2 variations of burst sequence
 - Sequential
 - Interleave

- Programmable $\overline{\text{CE}}$ latency: 4
- Byte control by DQMB
- Refresh cycles: 8192 refresh cycles/64 ms
- 2 variations of refresh
 - Auto refresh
 - Self refresh

Ordering Information

Type No.	Frequency	CE latency	Package	Contact pad
HB52RF1289E2-75B	133 Mhz	4	168-pin dual lead out socket type	Gold

Pin Arrangement



1 V _{SS} 43 V _{SS} 85 V _{SS} 127 V _{SS} 2 DQ0 44 NC 86 DQ32 128 CKE0 3 DQ1 45 \$\overline{S}\overline{2}\$ 87 DQ33 129 \$\overline{3}\overline{3}\$ 4 DQ2 46 DQMB2 88 DQ34 130 DQMB6 5 DQ3 47 DQMB3 89 DQ35 131 DQMB7 6 V _{CC} 48 NC 90 V _{CC} 132 NC 7 DQ4 49 V _{CC} 91 DQ36 133 V _{CC} 8 DQ5 50 NC 92 DQ37 134 NC 9 DQ6 51 NC 93 DQ38 135 NC 10 DQ7 52 CB2 94 DQ39 136 CB6 11 DQ8 53 CB3 95 DQ40	Pin No.	Pin name						
2 DQ0 44 NC 86 DQ32 128 CKE0 3 DQ1 45 \$\overline{\overline{5}}\$2 87 DQ33 129 \$\overline{3}\$3 4 DQ2 46 DQMB2 88 DQ34 130 DQMB6 5 DQ3 47 DQMB3 89 DQ35 131 DQMB7 6 V _{CC} 48 NC 90 V _{CC} 132 NC 7 DQ4 49 V _{CC} 91 DQ36 133 V _{CC} 8 DQ5 50 NC 92 DQ37 134 NC 9 DQ6 51 NC 93 DQ38 135 NC 10 DQ7 52 CB2 94 DQ39 136 CB6 11 DQ8 53 CB3 95 DQ40 137 CB7 12 V _{SS} 54 V _{SS} 96 V _{SS} 138 <td>1</td> <td>V_{SS}</td> <td>43</td> <td>V_{SS}</td> <td>85</td> <td>V_{SS}</td> <td>127</td> <td>V_{SS}</td>	1	V _{SS}	43	V _{SS}	85	V _{SS}	127	V _{SS}
4 DQ2 46 DQMB2 88 DQ34 130 DQMB6 5 DQ3 47 DQMB3 89 DQ35 131 DQMB7 6 V _{CC} 48 NC 90 V _{CC} 132 NC 7 DQ4 49 V _{CC} 91 DQ36 133 V _{CC} 8 DQ5 50 NC 92 DQ37 134 NC 9 DQ6 51 NC 93 DQ38 135 NC 10 DQ7 52 CB2 94 DQ39 136 CB6 11 DQ8 53 CB3 95 DQ40 137 CB7 12 V _{SS} 54 V _{SS} 96 V _{SS} 138 V _{SS} 13 DQ9 55 DQ16 97 DQ41 139 DQ48 14 DQ10 56 DQ17 98 DQ42 140 DQ49	2		44		86		128	
5 DQ3 47 DQMB3 89 DQ35 131 DQMB7 6 V _{CC} 48 NC 90 V _{CC} 132 NC 7 DQ4 49 V _{CC} 91 DQ36 133 V _{CC} 8 DQ5 50 NC 92 DQ37 134 NC 9 DQ6 51 NC 93 DQ38 135 NC 10 DQ7 52 CB2 94 DQ39 136 CB6 11 DQ8 53 CB3 95 DQ40 137 CB7 12 V _{SS} 54 V _{SS} 96 V _{SS} 138 V _{SS} 13 DQ9 55 DQ16 97 DQ41 139 DQ48 14 DQ10 56 DQ17 98 DQ42 140 DQ49 15 DQ11 57 DQ18 99 DQ43 141 DQ50	3	DQ1	45	S2	87	DQ33	129	S3
6 V _{CC} 48 NC 90 V _{CC} 132 NC 7 DQ4 49 V _{CC} 91 DQ36 133 V _{CC} 8 DQ5 50 NC 92 DQ37 134 NC 9 DQ6 51 NC 93 DQ38 135 NC 10 DQ7 52 CB2 94 DQ39 136 CB6 11 DQ8 53 CB3 95 DQ40 137 CB7 12 V _{SS} 54 V _{SS} 96 V _{SS} 138 V _{SS} 13 DQ9 55 DQ16 97 DQ41 139 DQ48 14 DQ10 56 DQ17 98 DQ42 140 DQ49 15 DQ11 57 DQ18 99 DQ43 141 DQ50 16 DQ12 58 DQ19 100 DQ44 142 DQ51	4	DQ2	46	DQMB2	88	DQ34	130	DQMB6
7 DQ4 49 V _{CC} 91 DQ36 133 V _{CC} 8 DQ5 50 NC 92 DQ37 134 NC 9 DQ6 51 NC 93 DQ38 135 NC 10 DQ7 52 CB2 94 DQ39 136 CB6 11 DQ8 53 CB3 95 DQ40 137 CB7 12 V _{SS} 54 V _{SS} 96 V _{SS} 138 V _{SS} 13 DQ9 55 DQ16 97 DQ41 139 DQ48 14 DQ10 56 DQ17 98 DQ42 140 DQ49 15 DQ11 57 DQ18 99 DQ43 141 DQ50 16 DQ12 58 DQ19 100 DQ44 142 DQ51 17 DQ13 59 V _{CC} 101 DQ45 143 V _{CC} <td>5</td> <td>DQ3</td> <td>47</td> <td>DQMB3</td> <td>89</td> <td>DQ35</td> <td>131</td> <td>DQMB7</td>	5	DQ3	47	DQMB3	89	DQ35	131	DQMB7
8 DQ5 50 NC 92 DQ37 134 NC 9 DQ6 51 NC 93 DQ38 135 NC 10 DQ7 52 CB2 94 DQ39 136 CB6 11 DQ8 53 CB3 95 DQ40 137 CB7 12 V _{SS} 54 V _{SS} 96 V _{SS} 138 V _{SS} 13 DQ9 55 DQ16 97 DQ41 139 DQ48 14 DQ10 56 DQ17 98 DQ42 140 DQ49 15 DQ11 57 DQ18 99 DQ43 141 DQ50 16 DQ12 58 DQ19 100 DQ44 142 DQ51 17 DQ13 59 V _{CC} 101 DQ45 143 V _{CC} 18 V _{CC} 60 DQ20 102 V _{CC} 144 DQ52	6	V _{CC}	48	NC	90	V _{CC}	132	NC
9 DQ6 51 NC 93 DQ38 135 NC 10 DQ7 52 CB2 94 DQ39 136 CB6 11 DQ8 53 CB3 95 DQ40 137 CB7 12 V _{SS} 54 V _{SS} 96 V _{SS} 138 V _{SS} 13 DQ9 55 DQ16 97 DQ41 139 DQ48 14 DQ10 56 DQ17 98 DQ42 140 DQ49 15 DQ11 57 DQ18 99 DQ43 141 DQ50 16 DQ12 58 DQ19 100 DQ44 142 DQ51 17 DQ13 59 V _{CC} 101 DQ45 143 V _{CC} 18 V _{CC} 60 DQ20 102 V _{CC} 144 DQ52 19 DQ14 61 NC 103 DQ46 145 <tn< td=""><td>7</td><td>DQ4</td><td>49</td><td>V_{CC}</td><td>91</td><td>DQ36</td><td>133</td><td>V_{CC}</td></tn<>	7	DQ4	49	V _{CC}	91	DQ36	133	V _{CC}
10 DQ7 52 CB2 94 DQ39 136 CB6 11 DQ8 53 CB3 95 DQ40 137 CB7 12 V _{SS} 54 V _{SS} 96 V _{SS} 138 V _{SS} 13 DQ9 55 DQ16 97 DQ41 139 DQ48 14 DQ10 56 DQ17 98 DQ42 140 DQ49 15 DQ11 57 DQ18 99 DQ43 141 DQ50 16 DQ12 58 DQ19 100 DQ44 142 DQ51 17 DQ13 59 V _{CC} 101 DQ45 143 V _{CC} 18 V _{CC} 60 DQ20 102 V _{CC} 144 DQ52 19 DQ14 61 NC 103 DQ46 145 NC 20 DQ15 62 NC 104 DQ47 146	8	DQ5	50	NC	92	DQ37	134	NC
11 DQ8 53 CB3 95 DQ40 137 CB7 12 V _{SS} 54 V _{SS} 96 V _{SS} 138 V _{SS} 13 DQ9 55 DQ16 97 DQ41 139 DQ48 14 DQ10 56 DQ17 98 DQ42 140 DQ49 15 DQ11 57 DQ18 99 DQ43 141 DQ50 16 DQ12 58 DQ19 100 DQ44 142 DQ51 17 DQ13 59 V _{CC} 101 DQ45 143 V _{CC} 18 V _{CC} 60 DQ20 102 V _{CC} 144 DQ52 19 DQ14 61 NC 103 DQ46 145 NC 20 DQ15 62 NC 104 DQ47 146 NC 21 CB0 63 NC 105 CB4 147 <t< td=""><td>9</td><td>DQ6</td><td>51</td><td>NC</td><td>93</td><td>DQ38</td><td>135</td><td>NC</td></t<>	9	DQ6	51	NC	93	DQ38	135	NC
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13 DQ9 55 DQ16 97 DQ41 139 DQ48 14 DQ10 56 DQ17 98 DQ42 140 DQ49 15 DQ11 57 DQ18 99 DQ43 141 DQ50 16 DQ12 58 DQ19 100 DQ44 142 DQ51 17 DQ13 59 V _{CC} 101 DQ45 143 V _{CC} 18 V _{CC} 60 DQ20 102 V _{CC} 144 DQ52 19 DQ14 61 NC 103 DQ46 145 NC 20 DQ15 62 NC 104 DQ47 146 NC 21 CB0 63 NC 105 CB4 147 REGE 22 CB1 64 V _{SS} 106 CB5 148 V _{SS} 23 V _{SS} 65 DQ21 107 V _{SS} 149	11	DQ8	53	CB3	95	DQ40	137	CB7
13 DQ9 55 DQ16 97 DQ41 139 DQ48 14 DQ10 56 DQ17 98 DQ42 140 DQ49 15 DQ11 57 DQ18 99 DQ43 141 DQ50 16 DQ12 58 DQ19 100 DQ44 142 DQ51 17 DQ13 59 V _{CC} 101 DQ45 143 V _{CC} 18 V _{CC} 60 DQ20 102 V _{CC} 144 DQ52 19 DQ14 61 NC 103 DQ46 145 NC 20 DQ15 62 NC 104 DQ47 146 NC 21 CB0 63 NC 105 CB4 147 REGE 22 CB1 64 V _{SS} 106 CB5 148 V _{SS} 23 V _{SS} 65 DQ21 107 V _{SS} 149	12	V _{SS}	54	V _{SS}	96	V _{SS}	138	V _{SS}
15 DQ11 57 DQ18 99 DQ43 141 DQ50 16 DQ12 58 DQ19 100 DQ44 142 DQ51 17 DQ13 59 V _{CC} 101 DQ45 143 V _{CC} 18 V _{CC} 60 DQ20 102 V _{CC} 144 DQ52 19 DQ14 61 NC 103 DQ46 145 NC 20 DQ15 62 NC 104 DQ47 146 NC 20 DQ15 62 NC 104 DQ47 146 NC 21 CB0 63 NC 105 CB4 147 REGE 22 CB1 64 V _{SS} 106 CB5 148 V _{SS} 23 V _{SS} 65 DQ21 107 V _{SS} 149 DQ53 24 NC 66 DQ22 108 NC 150	13		55		97	DQ41	139	
16 DQ12 58 DQ19 100 DQ44 142 DQ51 17 DQ13 59 V _{CC} 101 DQ45 143 V _{CC} 18 V _{CC} 60 DQ20 102 V _{CC} 144 DQ52 19 DQ14 61 NC 103 DQ46 145 NC 20 DQ15 62 NC 104 DQ47 146 NC 21 CB0 63 NC 105 CB4 147 REGE 22 CB1 64 V _{SS} 106 CB5 148 V _{SS} 23 V _{SS} 65 DQ21 107 V _{SS} 149 DQ53 24 NC 66 DQ22 108 NC 150 DQ54 25 NC 67 DQ23 109 NC 151 DQ55 26 V _{CC} 68 V _{SS} 110 V _{CC} 152	14	DQ10	56	DQ17	98	DQ42	140	DQ49
17 DQ13 59 V _{CC} 101 DQ45 143 V _{CC} 18 V _{CC} 60 DQ20 102 V _{CC} 144 DQ52 19 DQ14 61 NC 103 DQ46 145 NC 20 DQ15 62 NC 104 DQ47 146 NC 21 CB0 63 NC 105 CB4 147 REGE 22 CB1 64 V _{SS} 106 CB5 148 V _{SS} 23 V _{SS} 65 DQ21 107 V _{SS} 149 DQ53 24 NC 66 DQ22 108 NC 150 DQ54 25 NC 67 DQ23 109 NC 151 DQ55 26 V _{CC} 68 V _{SS} 110 V _{CC} 152 V _{SS} 27 W 69 DQ24 111 CE 153	15	DQ11	57	DQ18	99	DQ43	141	DQ50
18 V _{CC} 60 DQ20 102 V _{CC} 144 DQ52 19 DQ14 61 NC 103 DQ46 145 NC 20 DQ15 62 NC 104 DQ47 146 NC 21 CB0 63 NC 105 CB4 147 REGE 22 CB1 64 V _{SS} 106 CB5 148 V _{SS} 23 V _{SS} 65 DQ21 107 V _{SS} 149 DQ53 24 NC 66 DQ22 108 NC 150 DQ54 25 NC 67 DQ23 109 NC 151 DQ55 26 V _{CC} 68 V _{SS} 110 V _{CC} 152 V _{SS} 27 W 69 DQ24 111 CE 153 DQ56 28 DQMB0 70 DQ25 112 DQMB4 154	16	DQ12	58	DQ19	100	DQ44	142	DQ51
18 V _{CC} 60 DQ20 102 V _{CC} 144 DQ52 19 DQ14 61 NC 103 DQ46 145 NC 20 DQ15 62 NC 104 DQ47 146 NC 21 CB0 63 NC 105 CB4 147 REGE 22 CB1 64 V _{SS} 106 CB5 148 V _{SS} 23 V _{SS} 65 DQ21 107 V _{SS} 149 DQ53 24 NC 66 DQ22 108 NC 150 DQ54 25 NC 67 DQ23 109 NC 151 DQ55 26 V _{CC} 68 V _{SS} 110 V _{CC} 152 V _{SS} 27 W 69 DQ24 111 CE 153 DQ56 28 DQMB0 70 DQ25 112 DQMB4 154	17	DQ13	59	V _{CC}	101	DQ45	143	V _{CC}
20 DQ15 62 NC 104 DQ47 146 NC 21 CB0 63 NC 105 CB4 147 REGE 22 CB1 64 V _{SS} 106 CB5 148 V _{SS} 23 V _{SS} 65 DQ21 107 V _{SS} 149 DQ53 24 NC 66 DQ22 108 NC 150 DQ54 25 NC 67 DQ23 109 NC 151 DQ55 26 V _{CC} 68 V _{SS} 110 V _{CC} 152 V _{SS} 27 W 69 DQ24 111 CE 153 DQ56 28 DQMB0 70 DQ25 112 DQMB4 154 DQ57 29 DQMB1 71 DQ26 113 DQMB5 155 DQ58 30 S0 72 DQ27 114 S1 156	18	V _{CC}	60		102	V _{CC}	144	
21 CB0 63 NC 105 CB4 147 REGE 22 CB1 64 V _{SS} 106 CB5 148 V _{SS} 23 V _{SS} 65 DQ21 107 V _{SS} 149 DQ53 24 NC 66 DQ22 108 NC 150 DQ54 25 NC 67 DQ23 109 NC 151 DQ55 26 V _{CC} 68 V _{SS} 110 V _{CC} 152 V _{SS} 27 W 69 DQ24 111 CE 153 DQ56 28 DQMB0 70 DQ25 112 DQMB4 154 DQ57 29 DQMB1 71 DQ26 113 DQMB5 155 DQ58 30 S0 72 DQ27 114 S1 156 DQ59 31 NC 73 V _{CC} 115 RE 157 <td< td=""><td>19</td><td></td><td>61</td><td>NC</td><td>103</td><td></td><td>145</td><td>NC</td></td<>	19		61	NC	103		145	NC
22 CB1 64 V _{SS} 106 CB5 148 V _{SS} 23 V _{SS} 65 DQ21 107 V _{SS} 149 DQ53 24 NC 66 DQ22 108 NC 150 DQ54 25 NC 67 DQ23 109 NC 151 DQ55 26 V _{CC} 68 V _{SS} 110 V _{CC} 152 V _{SS} 27 W 69 DQ24 111 CE 153 DQ56 28 DQMB0 70 DQ25 112 DQMB4 154 DQ57 29 DQMB1 71 DQ26 113 DQMB5 155 DQ58 30 S0 72 DQ27 114 S1 156 DQ59 31 NC 73 V _{CC} 115 RE 157 V _{CC} 32 V _{SS} 74 DQ28 116 V _{SS} 158	20	DQ15	62	NC	104	DQ47	146	NC
23 V _{SS} 65 DQ21 107 V _{SS} 149 DQ53 24 NC 66 DQ22 108 NC 150 DQ54 25 NC 67 DQ23 109 NC 151 DQ55 26 V _{CC} 68 V _{SS} 110 V _{CC} 152 V _{SS} 27 W 69 DQ24 111 CE 153 DQ56 28 DQMB0 70 DQ25 112 DQMB4 154 DQ57 29 DQMB1 71 DQ26 113 DQMB5 155 DQ58 30 S0 72 DQ27 114 S1 156 DQ59 31 NC 73 V _{CC} 115 RE 157 V _{CC} 32 V _{SS} 74 DQ28 116 V _{SS} 158 DQ60 33 A0 75 DQ29 117 A1 159	21	CB0	63	NC	105	CB4	147	REGE
23 V _{SS} 65 DQ21 107 V _{SS} 149 DQ53 24 NC 66 DQ22 108 NC 150 DQ54 25 NC 67 DQ23 109 NC 151 DQ55 26 V _{CC} 68 V _{SS} 110 V _{CC} 152 V _{SS} 27 W 69 DQ24 111 CE 153 DQ56 28 DQMB0 70 DQ25 112 DQMB4 154 DQ57 29 DQMB1 71 DQ26 113 DQMB5 155 DQ58 30 S0 72 DQ27 114 S1 156 DQ59 31 NC 73 V _{CC} 115 RE 157 V _{CC} 32 V _{SS} 74 DQ28 116 V _{SS} 158 DQ60 33 A0 75 DQ29 117 A1 159	22	CB1	64	V _{SS}	106	CB5	148	V _{SS}
24 NC 66 DQ22 108 NC 150 DQ54 25 NC 67 DQ23 109 NC 151 DQ55 26 V _{CC} 68 V _{SS} 110 V _{CC} 152 V _{SS} 27 W 69 DQ24 111 CE 153 DQ56 28 DQMB0 70 DQ25 112 DQMB4 154 DQ57 29 DQMB1 71 DQ26 113 DQMB5 155 DQ58 30 S0 72 DQ27 114 S1 156 DQ59 31 NC 73 V _{CC} 115 RE 157 V _{CC} 32 V _{SS} 74 DQ28 116 V _{SS} 158 DQ60 33 A0 75 DQ29 117 A1 159 DQ61 34 A2 76 DQ30 118 A3 160 DQ	23	V _{SS}	65		107	V _{SS}	149	
26 V _{CC} 68 V _{SS} 110 V _{CC} 152 V _{SS} 27 W 69 DQ24 111 CE 153 DQ56 28 DQMB0 70 DQ25 112 DQMB4 154 DQ57 29 DQMB1 71 DQ26 113 DQMB5 155 DQ58 30 S0 72 DQ27 114 S1 156 DQ59 31 NC 73 V _{CC} 115 RE 157 V _{CC} 32 V _{SS} 74 DQ28 116 V _{SS} 158 DQ60 33 A0 75 DQ29 117 A1 159 DQ61 34 A2 76 DQ30 118 A3 160 DQ62	24		66	DQ22	108		150	DQ54
27 W 69 DQ24 111 CE 153 DQ56 28 DQMB0 70 DQ25 112 DQMB4 154 DQ57 29 DQMB1 71 DQ26 113 DQMB5 155 DQ58 30 S0 72 DQ27 114 S1 156 DQ59 31 NC 73 V _{CC} 115 RE 157 V _{CC} 32 V _{SS} 74 DQ28 116 V _{SS} 158 DQ60 33 A0 75 DQ29 117 A1 159 DQ61 34 A2 76 DQ30 118 A3 160 DQ62	25	NC	67	DQ23	109	NC	151	DQ55
27 W 69 DQ24 111 CE 153 DQ56 28 DQMB0 70 DQ25 112 DQMB4 154 DQ57 29 DQMB1 71 DQ26 113 DQMB5 155 DQ58 30 \$\overline{S0}\$ 72 DQ27 114 \$\overline{S1}\$ 156 DQ59 31 NC 73 V _{CC} 115 \$\overline{RE}\$ 157 V _{CC} 32 V _{SS} 74 DQ28 116 V _{SS} 158 DQ60 33 A0 75 DQ29 117 A1 159 DQ61 34 A2 76 DQ30 118 A3 160 DQ62	26	V _{CC}	68	V _{SS}	110	V _{CC}	152	V _{SS}
29 DQMB1 71 DQ26 113 DQMB5 155 DQ58 30 \$\overline{S0}\$ 72 DQ27 114 \$\overline{S1}\$ 156 DQ59 31 NC 73 V _{CC} 115 \$\overline{RE}\$ 157 V _{CC} 32 V _{SS} 74 DQ28 116 V _{SS} 158 DQ60 33 A0 75 DQ29 117 A1 159 DQ61 34 A2 76 DQ30 118 A3 160 DQ62	27		69		111		153	
30 \$\overline{\sigma}\$0 72 DQ27 114 \$\overline{\sigma}\$1 156 DQ59 31 NC 73 V _{CC} 115 \$\overline{\sigma}\$E 157 V _{CC} 32 V _{SS} 74 DQ28 116 V _{SS} 158 DQ60 33 A0 75 DQ29 117 A1 159 DQ61 34 A2 76 DQ30 118 A3 160 DQ62	28	DQMB0	70	DQ25	112	DQMB4	154	DQ57
31 NC 73 V _{CC} 115 RE 157 V _{CC} 32 V _{SS} 74 DQ28 116 V _{SS} 158 DQ60 33 A0 75 DQ29 117 A1 159 DQ61 34 A2 76 DQ30 118 A3 160 DQ62	29	DQMB1	71	DQ26	113	DQMB5	155	DQ58
32 V _{SS} 74 DQ28 116 V _{SS} 158 DQ60 33 A0 75 DQ29 117 A1 159 DQ61 34 A2 76 DQ30 118 A3 160 DQ62	30	S0	72	DQ27	114	S1	156	DQ59
32 V _{SS} 74 DQ28 116 V _{SS} 158 DQ60 33 A0 75 DQ29 117 A1 159 DQ61 34 A2 76 DQ30 118 A3 160 DQ62	31	NC	73	V _{CC}	115	RE	157	V _{CC}
33 A0 75 DQ29 117 A1 159 DQ61 34 A2 76 DQ30 118 A3 160 DQ62	32	V _{SS}	74		116	V _{SS}	158	
	33		75	DQ29	117		159	DQ61
35 A4 77 DQ31 119 A5 161 DQ63	34	A2	76	DQ30	118	A3	160	DQ62
	35	A4	77	DQ31	119	A5	161	DQ63

Pin No.	Pin name						
36	A6	78	V _{SS}	120	A7	162	V _{SS}
37	A8	79	CK2	121	A9	163	CK3
38	A10 (AP)	80	NC	122	BA0	164	NC
39	BA1	81	WP	123	A11	165	SA0
40	V _{CC}	82	SDA	124	V _{CC}	166	SA1
41	V _{CC}	83	SCL	125	CK1	167	SA2
42	CK0	84	V _{CC}	126	A12	168	V _{CC}

Pin Description

Pin name	Function
A0 to\~A12	Address input
	Row addressA0 to A12
	Column addressA0 to A9, A11
BA0/BA1	Bank select addressBA0/BA1
DQ0 to DQ63	Data input/output
CB0 to CB7	Check bit (Data input/output)
S0 to S3	Chip select input
RE	Row enable (RAS) input
CE	Column enable (CAS) input
W	Write enable input
DQMB0 to DQMB7	Byte data mask
CK0 to CK3	Clock input
CKE0	Clock enable input
WP	Write protect for serial PD
REGE*1	Register enable
SDA	Data input/output for serial PD
SCL	Clock input for serial PD
SA0 to SA2	Serial address input
V _{CC}	Primary positive power supply
V _{SS}	Ground
NC	No connection

Note:

1.REGE is the Register Enable pin which permits the DIMM to operate in "buffered" mode and "registered" mode. To conform to this specification, mother boards must pull this pin to high state ("registerd" mode).

Serial PD Matrix*1

Byte No.	Function described	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Hex val- ue	Comments
0	Number of bytes used by module manufacturer	1	0	0	0	0	0	0	0	80	128
1	Total SPD memory size	0	0	0	0	1	0	0	0	80	256 byte
2	Memory type	0	0	0	0	0	1	0	0	04	SDRAM
3	Number of row addresses bits	0	0	0	0	1	1	0	1	0D	13
4	Number of column addresses bits	0	0	0	0	1	0	1	1	0B	11
5	Number of banks	0	0	0	0	0	0	1	0	02	2
6	Module data width	0	1	0	0	1	0	0	0	48	72 bit
7	Module data width (continued)	0	0	0	0	0	0	0	0	00	0 (+)
8	Module interface signal levels	0	0	0	0	0	0	0	1	01	LVTTL
9	SDRAM <u>cycle</u> time (highest CE latency) 7.5 ns	0	1	1	1	0	1	0	1	75	CL = 3
10	SDRAM access from Clock (highest CE latency) 5.4 ns	0	1	0	1	0	1	0	0	54	*5
11	Module configuration type	0	0	0	0	0	0	1	0	02	ECC
12	Refresh rate/type	1	0	0	0	0	0	1	0	82	Normal (7.8125 μs) Self refresh
13	SDRAM width	0	0	0	0	0	1	0	0	04	64M × 4
14	Error checking SDRAM width	0	0	0	0	0	1	0	0	04	× 4
15	SDRAM device attributes: minimum clock delay for back- to-back random column addresses	0	0	0	0	0	0	0	1	01	1 CLK
16	SDRAM device attributes: Burst lengths supported	0	0	0	0	1	1	1	1	0F	1, 2, 4, 8
17	SDRAM device attributes: number of banks on SDRAM device	0	0	0	0	0	1	0	0	04	4
18	SDRAM device attributes: CE latency	0	0	0	0	0	1	1	0	06	2/3
19	SDRAM device attributes: S latency	0	0	0	0	0	0	0	1	01	0

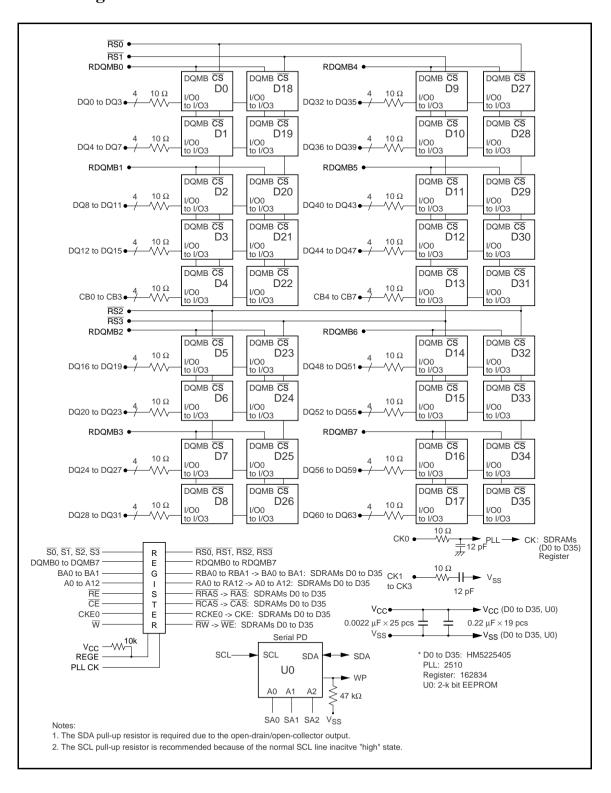
Byte No.	Function described	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Hex val- ue	Comments
20	SDRAM device attributes: W latency	0	0	0	0	0	0	0	1	01	0
21	SDRAM device attributes	0	0	0	1	0	1	1	0	16	Registered
22	SDRAM device attributes: General	0	0	0	0	1	1	1	0	0E	V _{CC} ± 10%
23	SDRAM cycle time (2nd highest CE latency) 10 ns	1	0	1	0	0	0	0	0	A0	CL = 2 *5
24	SDRAM access from Clock (2nd highest CE latency) 6 ns	0	1	1	0	0	0	0	0	60	* 5
25	SDRAM cycle time (3rd highest CE latency) Undefined	0	0	0	0	0	0	0	0	00	
26	SDRAM access from Clock (3rd highest \overline{CE} latency) Undefined	0	0	0	0	0	0	0	0	00	
27	Minimum row precharge time	0	0	0	1	0	1	0	0	14	20 ns
28	Row active to row active min	0	0	0	0	1	1	1	1	0F	15 ns
29	RE to CE delay min	0	0	0	1	0	1	0	0	14	20 ns
30	Minimum RE pulse width	0	0	1	0	1	1	0	1	2D	45 ns
31	Density of each bank on module	1	0	0	0	0	0	0	0	80	2 bank 512M byte
32	Address and command signal input setup time	0	0	0	1	0	1	0	1	15	1.5 ns* ⁵
33	Address and command signal input hold time	0	0	0	0	1	0	0	0	08	0.8 ns* ⁵
34	Data signal input setup time	0	0	0	1	0	1	0	1	15	1.5 ns* ⁵
35	Data signal input hold time	0	0	0	0	1	0	0	0	08	0.8 ns* ⁵
36 to 61	Superset information	0	0	0	0	0	0	0	0	00	Future use
62	SPD data revision code	0	0	0	0	0	0	1	0	02	JEDEC2
63	Checksum for bytes 0 to 62	1	0	1	0	0	1	0	0	A4	164
64	Manufacturer's JEDEC ID code	0	0	0	0	0	1	1	1	07	HITACHI
65 to 71	Manufacturer's JEDEC ID code	0	0	0	0	0	0	0	0	00	
72	Manufacturing location	×	×	×	×	×	×	×	×	××	*2 (ASCII- 8bit code)
73	Manufacturer's part number	0	1	0	0	1	0	0	0	48	Н
74	Manufacturer's part number	0	1	0	0	0	0	1	0	42	В
75	Manufacturer's part number	0	0	1	1	0	1	0	1	35	5
76	Manufacturer's part number	0	0	1	1	0	0	1	0	32	2
77	Manufacturer's part number	0	1	0	1	0	0	1	0	52	R
78	Manufacturer's part number	0	1	0	0	0	1	1	0	46	F
79	Manufacturer's part number	0	0	1	1	0	0	0	1	31	1
80	Manufacturer's part	0	0	1	1	0	0	1	0	32	2
81	Manufacturer's part number	0	0	1	1	1	0	0	0	38	8
82	Manufacturer's part number	0	0	1	1	1	0	0	1	39	9

Byte		Bit	Hex val-								
No.	Function described	7	6	5	4	3	2	1	0	ue	Comments
83	Manufacturer's part number	0	1	0	0	0	1	0	1	45	E
84	Manufacturer's part number	0	0	1	1	0	0	1	0	32	2
85	Manufacturer's part number	0	0	1	0	1	1	0	1	2D	_
86	Manufacturer's part number	0	0	1	1	0	1	1	1	37	7
87	Manufacturer's part number	0	0	1	1	0	1	0	1	35	5
88	Manufacturer's part number	0	1	0	0	0	0	1	0	42	В
89	Manufacturer's part number	0	0	1	0	0	0	0	0	20	(Space)
90	Manufacturer's part number	0	0	1	0	0	0	0	0	20	(Space)
91	Revision code	0	0	1	1	0	0	0	0	30	Initial
92	Revision code	0	0	1	0	0	0	0	0	20	(Space)
93	Manufacturing date	×	×	×	×	×	×	×	×	××	Year code (BCD)
94	Manufacturing date	×	×	×	×	×	×	×	×	××	Week code (BCD)
95 to 98	Assembly serial number	*3									
99 to 125	Manufacturer specific data	_	_	_	_	_	_	_	_	_	*4
126	Reserved (Intel specification frequency)	0	1	1	0	0	1	0	0	64	
127	Reserved (Intel specification	1	0	0	0	0	1	1	1	87	

Notes:

- 1. All serial PD data are not protected. 0: Serial data, "driven Low", 1: Serial data, "driven High".
- 2.Byte72 is manufacturing location code. (ex: In case of Japan, byte72 is 4AH. 4AH shows "J" on ASCII code.)
- 3.Bytes 95 through 98 are assembly serial number.
- 4.All bits of 99 through 125 are not defined ("1" or "0").
- 5. These specifications are defined based on component specifiation, not module.

Block Diagram



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit	Note
	.,	-0.5 to V _{CC} + 0.5	.,	_
Voltage on any pin relative to V _{SS}	V _T	(≤ 4.6 (max))	V	1
Supply voltage relative to V _{SS}	V_{CC}	-0.5 to +4.6	V	1
Short circuit output current	lout	50	mA	
Power dissipation	P _T	18.0	W	
Operating temperature	Topr	0 to +55	°C	
Storage temperature	Tstg	-50 to +100	°C	

Note: 1.Respect to V_{SS}

DC Operating Conditions (Ta = 0 to $+55^{\circ}$ C)

Parameter	Symbol	Min	Max	Unit	Notes
Supply voltage	V _{CC}	3.0	3.6	V	1
	V _{SS}	0	0	V	3
Input high voltage	V _{IH}	2.0	V _{CC}	V	1, 4
Input low voltage	V _{IL}	0	0.8	V	1, 5
Ambient illuminance	_	_	100	lx	

Notes: 1.All voltage referred to V_{SS}

2. The supply voltage with all VCC and V_{CC}Q pins must be on the same level.

3. The supply voltage with all VSS and V_{SS}Q pins must be on the same level.

 $4.V_{IH}$ (max) = $V_{CC} + 2.0$ V for pulse width ≤ 3 ns at V_{CC} .

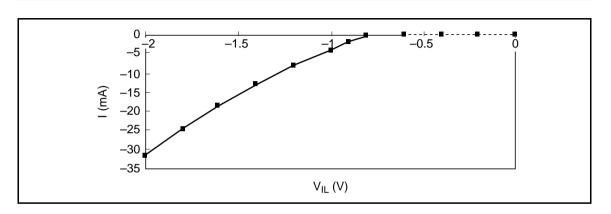
 $5.V_{IL}$ (min) = $V_{SS} - 2.0$ V for pulse width ≤ 3 ns at V_{SS} .

V_{II}/V_{IH} Clamp (Component characteristics)

This SDRAM component has V_{IL} and V_{IH} clamp for CK, CKE, $\overline{S},$ DQMB and DQ pins.

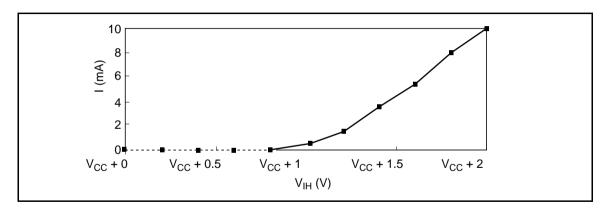
Minimum V_{IL} Clamp Current

V _{IL} (V)	I (mA)	
-2 -1.8	-32	
-1.8	-25	_
-1.6	–19	_
-1.4	-13	_
-1.2	-8	
-1	-4	_
-0.9	-2	_
-0.8	-0.6	_
-0.6	0	_
-1.6 -1.4 -1.2 -1 -0.9 -0.8 -0.6 -0.4 -0.2	0	
-0.2	0	
0	0	



Minimum V_{IH} Clamp Current (referred to $V_{IH}) \\$

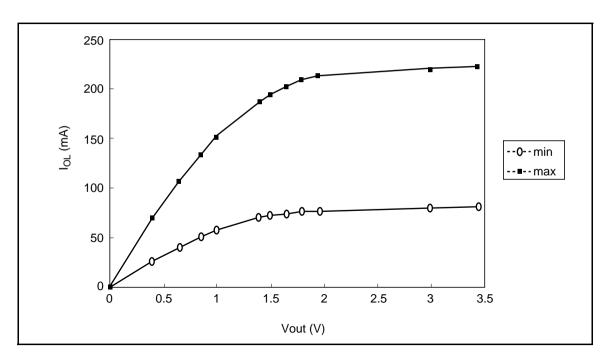
_V _{IH} (V)	I (mA)
V _{CC} + 2	10
V _{CC} + 1.8	8
V _{CC} + 1.6	5.5
V _{CC} + 1.4	3.5
V _{CC} + 1.2	1.5
V _{CC} + 2 V _{CC} + 1.8 V _{CC} + 1.6 V _{CC} + 1.4 V _{CC} + 1.2 V _{CC} + 1 V _{CC} + 0.8	0.3
V _{CC} + 0.8	0
V _{CC} + 0.6	0
V _{CC} + 0.4	0
V _{CC} + 0.2	0
V _{CC} + 0.4 V _{CC} + 0.2 V _{CC} + 0	0



I_{OL}/I_{OH} Characteristics (Component characteristics)

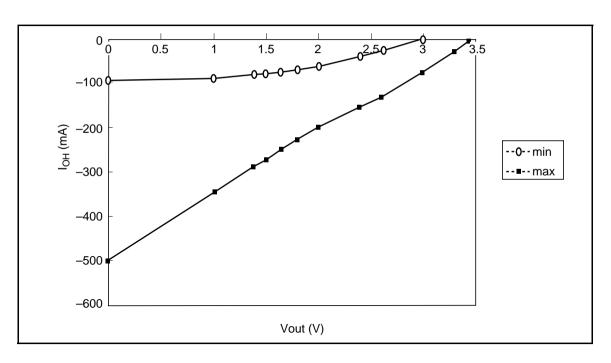
Output Low Current (IOL)

	I _{OL}	I _{OL}	
Vout (V)	Min (mA)	Max (mA)	
0	0	0	
0.4	27	71	
0.65	41	108	
0.85	51	134	
1	58	151	
1.4	70	188	
1.5	72	194	
1.65	75	203	
1.8	77	209	
1.95	77	212	
3	80	220	
3.45	81	223	



Output High Current (I_{OH}) (Ta = 0 to 55°C, V_{CC} = 3.0 V to 3.45 V, V_{SS} = 0 V)

	I _{OH}	I _{OH}	
Vout (V)	Min (mA)	Max (mA)	
3.45	-	-3	
3.3	_	-28	
3	0	-7 5	
2.6	– 21	-130	
2.4	-34	-154	
2	– 59	-197	
1.8	-67	-227	
1.65	-73	-248	
1.5	-78	-270	
1.4	– 81	-285	
1	-89	-345	
0	-93	-503	



DC Characteristics (Ta = 0 to 55°C, V_{CC} = 3.3 V \pm 0.3 V, V_{SS} = 0 V)

HB52RF1289E2-75B

Parameter	Symbol	Min	Max	Unit	Test conditions	Notes
Operating current					Burst length = 1	1, 2, 3
	I _{CC1}	_	3215	mA	$t_{RC} = min$	
Standby current in power down	I _{CC2P}	_	803	mA	$CKE = V_{IL}, t_{CK} = 12$ ns	6
Standby current in power down (input signal stable)	I _{CC2PS}	_	767	mA	$CKE = V_{IL}, t_{CK} = \infty$	7
Standby current in non power down	I _{CC2N}	_	1415	mA	CKE, $\overline{S} = V_{IH}$, t _{CK} = 12 ns	4
Active standby current in power down	I _{CC3P}	_	839	mA	$CKE = V_{IL}, t_{CK} = 12$ ns	1, 2, 6
Active standby current in non power down	I _{CC3N}	_	1775	mA	CKE, $\overline{S} = V_{IH}$, t _{CK} = 12 ns	1, 2, 4
Burst operating current	laa.	_	3575	mA	$t_{CK} = min, BL = 4$	1, 2, 5
Refresh current	I _{CC4}		3373	ША	t _{RC} = min	3
ivenesii cuiteni	I _{CC5}	_	5195	mA	IRC - IIIII	3
Self refresh current	I _{CC6}	_	803	mA	$V_{IH} \ge V_{CC} - 0.2 \text{ V}$ $V_{IL} \le 0.2 \text{ V}$	8
Input leakage current	I _{LI}	-10	10	μΑ	$0 \le Vin \le V_{CC}$	
Output leakage current	I _{LO}	-10	10	μΑ	$0 \le Vout \le V_{CC}$ DQ = disable	
Output high voltage	V _{OH}	2.4	_	V	$I_{OH} = -4 \text{ mA}$	
Output low voltage	V _{OL}	_	0.4	V	I _{OL} = 4 mA	

Notes:

- $1.I_{CC}$ depends on output load condition when the device is selected. I_{CC} (max) is specified at the output open condition.
- 2.One bank operation.
- 3.Input signals are changed once per one clock.
- 4. Input signals are changed once per two clocks.
- 5.Input signals are changed once per four clocks.
- 6. After power down mode, CK operating current.
- 7. After power down mode, no CK operating current.
- 8. After self refresh mode set, self refresh current.

Capacitance (Ta = 25°C, V_{CC} = 3.3 V \pm 0.3 V)

Parameter	Symbol	Max	Unit	Notes
Input capacitance (Address)	C _{I1}	25	pF	1, 2, 4
Input capacitance (RE, CE, W)	C _{I2}	25	pF	1, 2, 4
Input capacitance (CKE)	C _{I3}	45	pF	1, 2, 4
Input capacitance (S)	C _{I4}	20	pF	1, 2, 4
Input capacitance (CK)	C _{I5}	45	pF	1, 2, 4
Input capacitance (DQMB)	C _{I6}	20	pF	1, 2, 4
Input/Output capacitance (DQ)	C _{1/O1}	25	pF	1, 2, 3, 4

Notes:

- 1. Capacitance measured with Boonton Meter or effective capacitance measuring method.
- 2.Measurement condition: f = 1 MHz, 1.4 V bias, 200 mV swing.
- $3.DQMB = V_{IH}$ to disable Data-out.
- 4. This parameter is sampled and not 100% tested.

AC Characteristics (Ta = 0 to 55°C, V_{CC} = 3.3 V \pm 0.3 V, V_{SS} = 0 V)

	HITA- CHISym-	PC100				
Parameter	bol	Symbol	Min	Max	Unit	Notes
System clock cycle time	t _{CK}	Tclk	7.5	_	ns	1
CK high pulse width	t _{CKH}	Tch	3.4	_	ns	1
CK low pulse width	t _{CKL}	Tcl	3.4	_	ns	1
Access time from CK	t _{AC}	Tac	_	6.3	ns	1, 2
Data-out hold time	t _{OH}	Toh	1.8	_	ns	1, 2
CK to Data-out low impedance	t_{LZ}		1.1	_	ns	1, 2, 3
CK to Data-out high impedance	t_{HZ}		_	6.3	ns	1, 4
Data-in setup time	t _{DS}	Tsi	2.4	_	ns	1
Data in hold time	t _{DH}	Thi	1.7	_	ns	1
Address setup time	t _{AS}	Tsi	1.9	_	ns	1
Address hold time	t _{AH}	Thi	1.5	_	ns	1, 5
CKE setup time	t _{CES}	Tsi	1.9	_	ns	1, 5
CKE setup time for power down exit	t _{CESP}	Tpde	1.9	_	ns	1

AC Characteristics (Ta = 0 to 55°C, V_{CC} = 3.3 V \pm 0.3 V, V_{SS} = 0 V) (cont)

HB52RF1289E2-75B

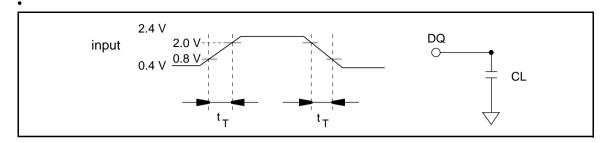
Parameter	HITA- CHISym- bol	PC100 Symbol	Min	Max	Unit	Notes
,				mux		
CKE hold time	t _{CEH}	Thi	1.5	_	ns	1
Command setup time	t_{CS}	Tsi	1.9	_	ns	1
Command hold time	t _{CH}	Thi	1.5	_	ns	1
Ref/Active to Ref/Active command period	t _{RC}	Trc	67.5	_	ns	1
Active to precharge command period	t _{RAS}	Tras	45	120000	ns	1
Active command to column command (same bank)	t _{RCD}	Trcd	22.5	_	ns	1
Precharge to active command period	t _{RP}	Trp	22.5	_	ns	1
Write recovery or data-in to precharge lead time	t _{DPL}	Tdpl	15	_	ns	1
Active (a) to Active (b) command period	t _{RRD}	Trrd	15	_	ns	1
Transition time (rise to fall)	t _T		1	5	ns	•
Refresh period	t _{REF}		_	64	ms	

Notes:

- 1.AC measurement assumes $t_T = 1$ ns. Reference level for timing of input signals is 1.5 V.
- 2. Access time is measured at 1.5 V. Load condition is $C_L = 50 \text{ pF}$.
- $3.t_{\rm LZ}$ (max) defines the time at which the outputs achieves the low impedance state.
- $4.t_{HZ}$ (max) defines the time at which the outputs achieves the high impedance state.
- 5.t_{CES} defines CKE setup time to CK rising edge except power down exit command.

Test Conditions

- Input and output timing reference levels: 1.5 V
- Input waveform and output load: See following figures
- Ambient illuminance: Under 100 lx



...........

Relationship Between Frequency and Minimum Latency

Parameter			HB52RF1289E2-75B	
Frequency (MHz)			133	
t _{CK} (ns)	HITA- CHI Symbol	PC100 Sym- bol	7.5	Notes
Active command to column command (same bank)	I _{RCD}		3	1
Active command to active command (same bank)	I _{RC}		9	= [I _{RAS} + I _{RP}] 1
Active command to precharge command (same bank)	I _{RAS}		6	1
Precharge command to active command (same bank)	I _{RP}		3	1
Write recovery or data-in to precharge command (same bank)	I _{DPL}	Tdpl	2	1
Active command to active command (different bank)	I _{RRD}		2	1
Self refresh exit time	I _{SREX}	Tsrx	2	2
Last data in to active command (Auto precharge, same bank)	I _{APW}	Tdal	5	= [l _{DPL} + l _{RP}]
Self refresh exit to command input	I _{SEC}		9	= [I _{RC}] 3
Precharge command to high impedance	I _{HZP}	Troh	4	
Last data out to active command (Auto precharge, same bank)	I _{APR}		0	
Last data out to precharge (early precharge)	I _{EP}		-3	
Column command to column command	I _{CCD}	Tccd	1	
Write command to data in latency	I_{WCD}	Tdwd	1	
DQMB to data in	I _{DID}	Tdqm	1	
DQMB to data out	I _{DOD}	Tdqz	3	
CKE to CK disable	I _{CLE}	Tcke	2	
Register set to active command	I _{RSA}	Tmrd	3	
S to command disable	I _{CDD}		0	
Power down exit to command input	I _{PEC}		1	

Pin Functions

. .

CK0 to CK3 (input pin): CK is the master clock input to this pin. The other input signals are referred at CK rising edge.

 $\overline{S0}$ to $\overline{S3}$ (input pin): When \overline{S} is Low, the command input cycle becomes valid. When \overline{S} is High, all inputs are ignored. However, internal operations (bank active, burst operations, etc.) are held.

 $\overline{\text{RE}}$, $\overline{\text{CE}}$ and $\overline{\text{W}}$ (input pins): Although these pin names are the same as those of conventional DRAMs, they function in a different way. These pins define operation commands (read, write, etc.) depending on the combination of their voltage levels. For details, refer to the command operation section.

A0 to A12 (input pins): Row address (AX0 to AX12) is determined by A0 to A12 level at the bank active command cycle CK rising edge. Column address (AY0 to AY9, AY11) is determined by A0 to A9, A11 level at the read or write command cycle CK rising edge. And this column address becomes burst access start address. A10 defines the precharge mode. When A10 = High at the precharge command cycle, all banks are precharged. But when A10 = Low at the precharge command cycle, only the bank that is selected by BA0/ BA1 (BA) is precharged.

BA0/BA1 (input pin): BA0/BA1 are bank select signal (BA). The memory array is divided into bank 0, bank 1, bank 2 and bank 3. If BA0 is Low and BA1 is Low, bank 0 is selected. If BA0 is High and BA1 is Low, bank 1 is selected. If BA0 is Low and BA1 is High, bank 2 is selected. If BA0 is High and BA1 is High, bank 3 is selected.

CKE0 (input pin): This pin determines whether or not the next CK is valid. If CKE is High, the next CK rising edge is valid. If CKE is Low, the next CK rising edge is invalid. This pin is used for power-down and clock suspend modes.

DQMB0 to DQMB7 (**input pins**): Read operation: If DQMB is High, the output buffer becomes High-Z. If the DOMB is Low, the output buffer becomes Low-Z.

Write operation: If DQMB is High, the previous data is held (the new data is not written). If DQMB is Low, the data is written.

DQ0 to DQ63, CB0 to CB7 (input/output pins): Data is input to and output from these pins.

V_{CC} (power supply pins): 3.3 V is applied.

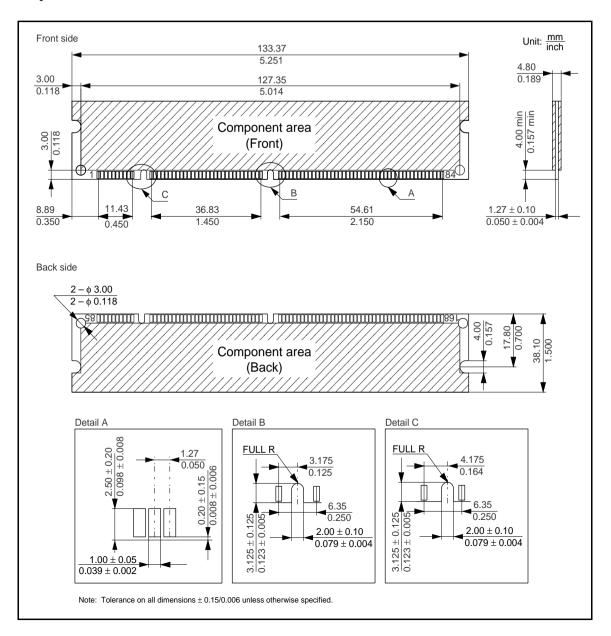
 V_{SS} (power supply pins): Ground is connected.

REGE (input pins): If REGE is High, the register is "registered" mode. If REGE is Low, the register is "buffered" mode.

Detailed Operation Part

Refer to the HM5225165B/HM5225805B/HM5225405B-75/A6/B6 datasheet.

Physical outline



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Revision Record

Rev.	Date	Contents of Modification	Drawn by	Approved by
0.0	Jun. 28, 1999	Initial issue (referred to HM5225165B/HM5225805B/HM5225405B- 75/A6/B6 rev 0.0)	A. Nakamura	K. Tsuneda
0.1	Aug. 10, 1999	(referred to HM5225165B/HM5225805B/HM5225405B-75/A6/B6 rev 0.0) Serial PD Matrix Byte 16: 8F to 0F Byte 63: 24 to A4		